

Bipolar Transistor

 $(-)50 V, (-)5 A, Low V_{CE}(sat),$ **Complementary Dual CPH5**

CPH5520

Features

- Composite Type with a PNP Transistor and an NPN Transistor Contained in One Package, Facilitating High-Density Mounting
- Ultrasmall Package Facilitate Miniaturization in End Products. (0.9 mm Mounting Height)
- This is a Pb-Free Device

Applications

• Relay Drivers, Lamp Drivers, Motor Drivers, Gate Drivers

Specifications

(): PNP

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-50)80	V
Collector-to-Emitter Voltage	V _{CEO}		(-50)50	٧
Emitter-to-Base Voltage	V _{EBO}		(-)6	٧
Collector Current	I _C		(-)2	Α
Collector Current (Pulse)	I _{CP}		(-)5	Α
Base Current	Ι _Β		(-)400	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600 mm ² × 0.8 mm) 1unit	0.9	W
Total Power Dissipation	P _T	Mounted on a ceramic board (600 mm ² × 0.8 mm)	1.2	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

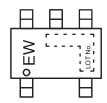
1



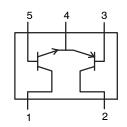
- 1: Collector (NPN TR)
- 2: Collector (PNP TR)
- 3: Base (PNP TR)
- 4: Emitter Common
- 5: Base (NPN TR)

CASE 318BC

MARKING DIAGRAM



ELECTRICAL CONNECTION



ORDERING INFORMATION

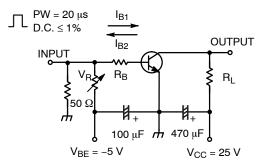
Device	Package	Shipping [†]
CPH5520-TL-E	CPH5 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

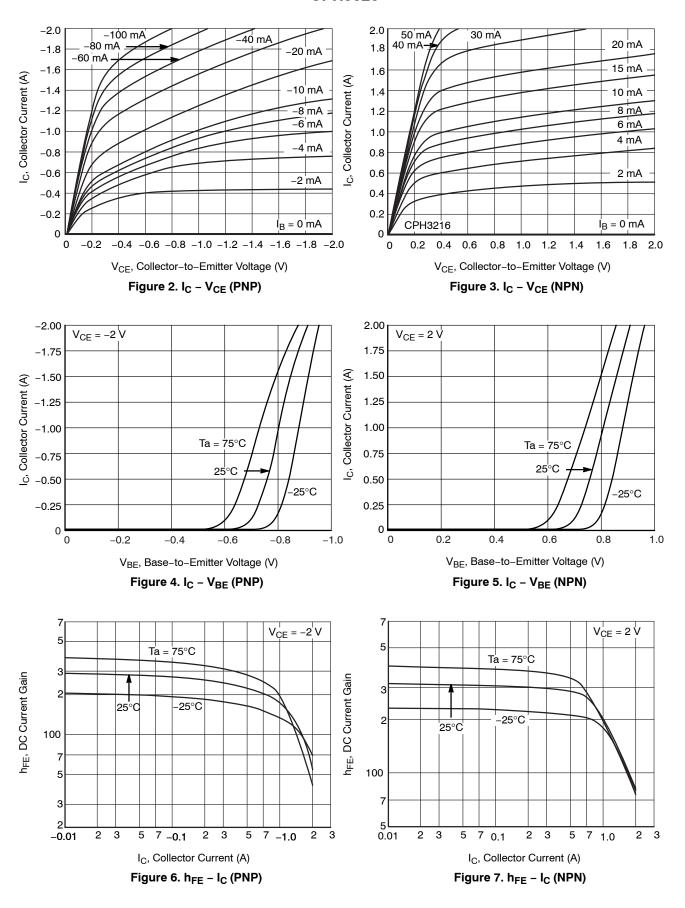
			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)40 V, I _E = 0 A	_	-	(-)1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)1	μΑ
DC Current Gain	h _{FE}	$V_{CE} = (-)2 \text{ V, } I_{C} = (-)100 \text{ mA}$	200	-	560	
Gain-Bandwidth Product	f _T	V _{CE} = (-)10 V, I _C = (-)300 mA	-	420	-	MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1 MHz	-	(16)8	-	pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = (-)1 A, I _B = (-)50 mA	-	(-165)130	(-330)260	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	$I_C = (-)1 \text{ A}, I_B = (-)50 \text{ mA}$		(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = (-)10 μA, I _E = 0 A	(-50)80	-	-	V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	$I_C = (-)1 \text{ mA}, R_{BE} = \infty$	(-50)50	-	-	V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = (-)10 μA, I _C = 0 A	(-)6	-	-	V
Turn-On Time	t _{on}	See specified Test Circuit	_	(35)35	-	ns
Storage Time	t _{stg}	1	-	(200)330	-	ns
Fall Time	t _f		_	(24)40	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



 $I_C = 10I_{B1} = -10I_{B2} = 0.7 \text{ A}$ For PNP, the polarity is reversed.

Figure 1. Switching Time Test Circuit



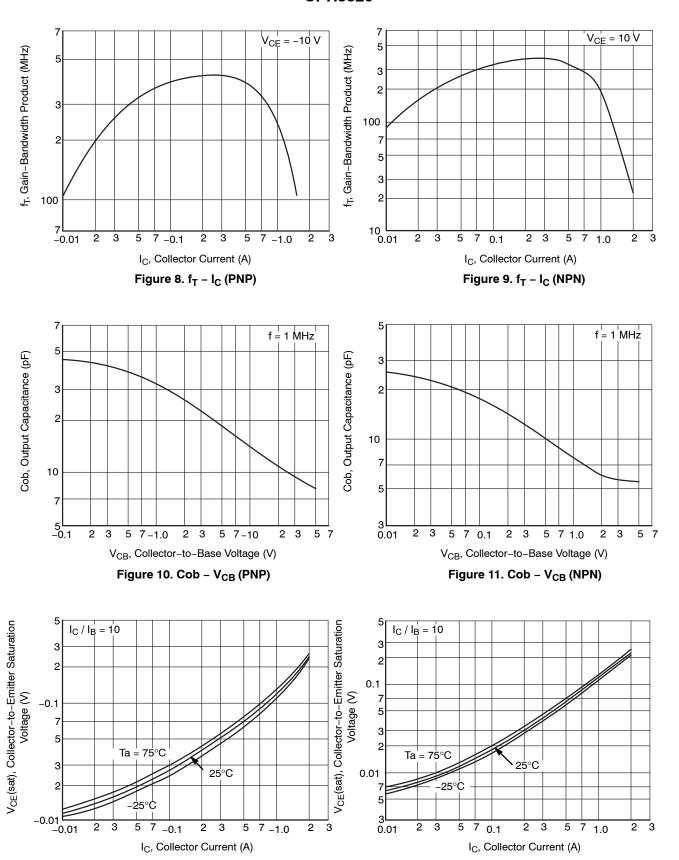


Figure 13. V_{CE}(sat) – I_C (NPN)

Figure 12. V_{CE}(sat) – I_C (PNP)

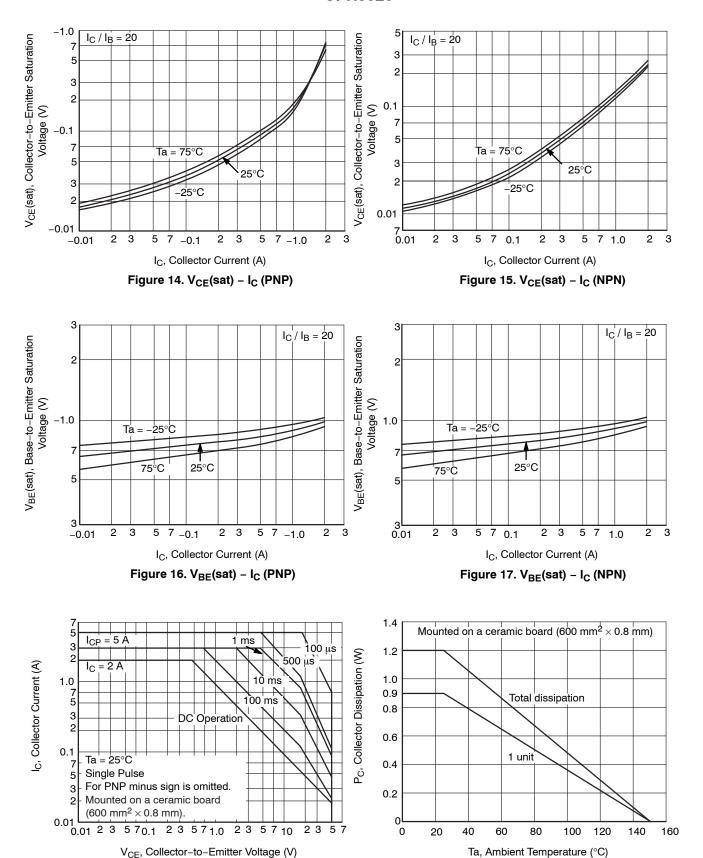
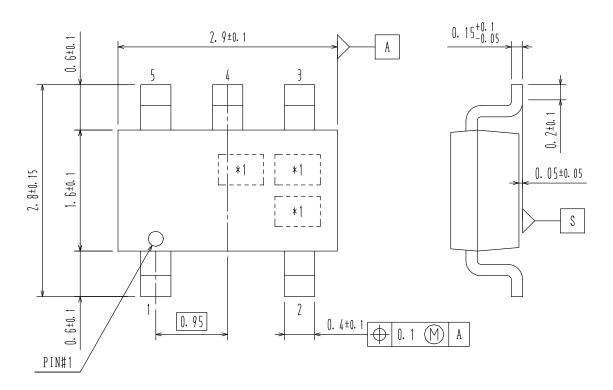


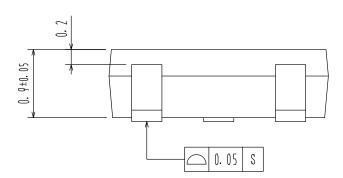
Figure 19. P_C - Ta (PNP/NPN)

Figure 18. ASO (PNP/NPN)

CPH5 CASE 318BC ISSUE O

DATE 30 NOV 2011





DOCUMENT NUMBER:	98AON65439E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	CPH5		PAGE 1 OF 1	

ON Semiconductor and III are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales